



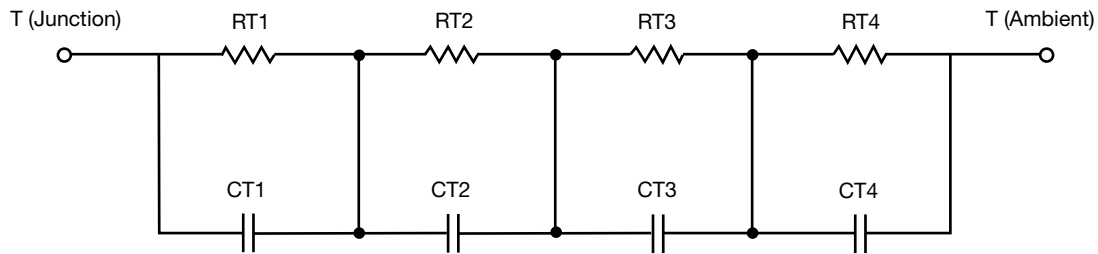
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	n/a	65.9736m	n/a
RT2	n/a	154.9962m	n/a
RT3	n/a	104.0378m	n/a
RT4	n/a	174.9924m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	n/a	29.0214m	n/a
CT2	n/a	348.0520m	n/a
CT3	n/a	7.0085m	n/a
CT4	n/a	308.3041m	n/a

Note
• n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



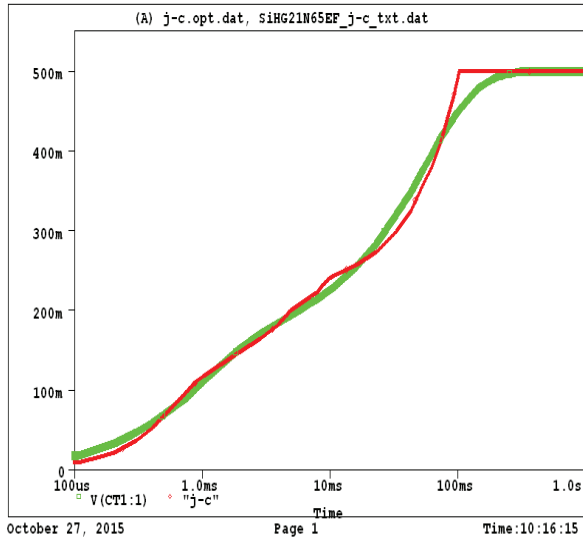
R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	n/a	117.5790m	n/a
RF2	n/a	51.2723m	n/a
RF3	n/a	36.4473m	n/a
RF4	n/a	294.7014m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	n/a	5.0737m	n/a
CF2	n/a	6.1225m	n/a
CF3	n/a	38.5894m	n/a
CF4	n/a	133.0345m	n/a

Note

- n/a indicates not applicable



SiHG21N65EF Tank j-c Temperature:27.0



SiHG21N65EF Filter j-c Temperature:27.0

